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(54) Liquid crystal display element having controlled storage capacitance

Flüssigkristallanzeigeelement mit kontrollierter Speicherkapazität

Elément d'affichage à cristal liquide à capacité de stockage contrôlée

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US-A- 5 040 875 **US-A- 5 368 915**
US-A- 6 022 753

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Description

BACKGROUND OF THE INVENTION

[0001] The present invention relates to a liquid crystal display element, and in particular to a thin film transistor active-matrix type liquid crystal display element provided with a storage capacity formed in a pixel area by a storage line disposed therein and a pixel electrode.

[0002] Liquid crystal display devices are widely used as a high-definition color display device for a notebook computer and a display monitor.

[0003] Among liquid crystal display elements, the simple matrix type and the active matrix type are well-known. The simple matrix type liquid crystal display element comprises a pair of opposing substrates, a first group of parallel strip electrodes disposed on an inner surface of one of the substrates, a second group of parallel strip electrodes disposed on an inner surface of the other substrate to intersect the first group of parallel strip electrodes, and a liquid crystal layer sandwiched between the substrates. The active matrix type liquid crystal display element comprises a pair of opposing substrates, a plurality of switching elements each provided for selecting a respective pixel and disposed on an inner surface of one of the substrates, and a liquid crystal layer sandwiched between the substrates.

[0004] The active matrix type liquid crystal display element is divided into the so-called vertical electric field type which usually called the TN (the Twisted Nematic) type and the so-called horizontal electric field type which is usually called the IPS (the In-Plane-Switching type). In the so-called vertical electric field type as represented by the TN type, two groups of strip electrodes for selection of pixels are disposed on inner surfaces of a pair of upper and lower substrates, respectively. In the so-called horizontal electric field type, two groups of electrodes for selection of pixels are disposed only on an inner surface of one of a pair of upper and lower substrates.

[0005] In the TN type active-matrix liquid crystal display element, liquid crystal molecules are oriented to be twisted through 90 degrees, for example, between a pair of opposing substrates. A pair of polarizers are disposed in front of and behind the liquid crystal display element, respectively, such that their absorption axes are at right angles (the arrangement of crossed nicols) with the absorption axis of a polarizer on the entrance side is parallel with or perpendicular to the rubbing direction of the entrance-side substrate.

[0006] In the TN type active-matrix liquid crystal display element, first suppose that no electric field is applied across the liquid crystal layer. The incident light is converted into a linearly polarized light by the entrance-side polarizer, the linearly polarized light propagates along the twist of the liquid crystal molecules, and then all of the linearly polarized light passes through the exit-side polarizer and provides a white display if an azimuthal angle of the transmission axis of the exit-side polarizer

is identical with that of the linearly polarized light entering the exit-side polarizer. This is the so-called normally open mode.

[0007] Next, suppose that an electric field is applied across the liquid crystal layer. The direction (director) of a unit vector representing the average direction of orientations of axes of liquid crystal molecules of the liquid crystal layer is perpendicular to the surface of the substrate, the azimuthal angle of the linearly polarized light entering the liquid crystal layer is not changed, and as a result, it is identical with that of the absorption angle of the exit-end polarizer and consequently, the liquid crystal display element provides a black display. For further detail, see "Basics and Application of Liquid Crystal," Industrial Research Association, Tokyo, 1991.

[0008] As described above, the TN type liquid crystal display element includes a pair of opposing transparent insulating substrates made of material such as glass, a liquid crystal layer sandwiched between the opposing glass substrates, a group of scanning signal lines (hereinafter also called gate signal lines) extending in the x direction and arranged in the y direction on the liquid-crystal layer side surface of one of the substrates in a system of rectangular co-ordinates, and a group of drain lines (hereinafter also called video signal lines) insulated from the gate signal lines, extending in the y direction, and arranged in the x direction.

[0009] A pixel area is formed in an area surrounded by two adjacent gate lines and two adjacent drain lines, and all the pixel areas form a display area. Formed in each pixel area are a thin film transistor (TFT) serving as an active element (a switching element), for example, and a transparent pixel electrode.

[0010] A scanning signal supplied to a gate line switch on a thin film transistor which, in turn, supplies a video signal to a pixel electrode from a drain line.

[0011] A capacitance formed by a dielectric of the lighted liquid crystal is not sufficient to maintain the ON (lighted) state of the pixel which has been driven by the thin film transistor during a specified period of time, and therefore an additional capacitance is provided to each pixel so as to replenish the shortage of the capacitance. The additional capacitance has been provided by overlaying a portion of the pixel electrode on the gate line with an insulating layer interposed therebetween.

[0012] On the other hand, a storage method is suggested which disposes a storage line in the pixel area and forms a capacitance (a storage capacitance) using a pixel electrode, the storage line and an insulating layer therebetween.

[0013] Storage type liquid crystal display devices are disclosed in Japanese Patent Application Laid-open No. Hei 11-231341 (laid-open on Aug. 27, 1999), Japanese Patent Application Laid-open No. 2000-221527 (laid-open on Aug. 11, 2000), and Japanese Utility Model Registration No. 2536632 (registered on Feb. 21, 1997).

[0014] FIG. 13 shows an equivalent circuit of a storage type liquid crystal display element. In the storage type

liquid crystal display element, a plurality of gate lines GL and a plurality of drain lines DL are disposed to intersect one another in a display area AR on one of a pair of opposing substrates, a thin film transistor TFT is disposed at each of intersections of the gate lines GL and the drain lines DL, and a plurality of storage lines STL are disposed between and parallel with the gate lines GL. Reference character ITO2 denotes a common electrode disposed on an inner surface of the other substrate.

[0015] A source electrode (the roles of source and drain may be exchanged in a driving cycle) of the thin film transistor TFT is connected to the pixel electrode ITO1, a liquid crystal capacitance C_{LC} is formed between the pixel electrode ITO1 and the common electrode ITO2 with a liquid crystal therebetween serving as a dielectric, and a storage capacity C_{STG} is formed between the pixel electrode ITO1 and the storage line STL.

[0016] The common electrode ITO2 is supplied with a specified voltage (preferably a fixed voltage) from a common-electrode driving circuit CDR, and the storage lines STL are supplied with a specified voltage (preferably a fixed voltage) from a storage-line driving circuit STR. Reference character GDR denotes a gate line driving circuit, DDR is a drain line driving circuit, CONT is a display control circuit for supplying display signals and timing signals.

[0017] FIG. 14 is a plan view of essential parts of a unit pixel and its vicinity formed on a substrate SUB1 of the storage type liquid crystal display element. In FIG. 14, certain of the shapes and dimensions are exaggerated for clarity.

[0018] FIG. 15 is a schematic cross-sectional view of the storage type liquid crystal display element taken along line XV-XV of FIG. 14.

[0019] In FIG. 14, each pixel is disposed in an area surrounded by two adjacent gate lines GL and two adjacent drain lines intersecting the gate lines GL, and is provided with a thin film transistor TFT at their intersection. The thin film transistor TFT is comprised of the gate line GL, an insulating film (not shown to avoid undue complication of the drawing) covering the gate line GL, a semiconductor layer 100 made of amorphous silicon with the insulating film formed on the insulating film, a pair of a source electrode SD1 and a drain electrode SD2 which are disposed to oppose each other on the semiconductor layer 100. A semiconductor layer integral with the semiconductor layer 100 is disposed below the drain line DL so as to reduce step heights. Reference character SH denotes light-shielding members, reference numeral 102 are openings made in the gate lines GL for the purpose of reducing line defects.

[0020] The pixel electrode ITO1 made of transparent conductive film is formed in the pixel area and is connected to the source electrode SD1 of the thin film transistor TFT. The storage line STL is formed in parallel with the gate lines GL, below the pixel electrode ITO1 with an insulating layer interposed (not shown for clarity in FIG. 14, but should be understood to be present) between the

pixel electrode ITO1 and the storage line STL in the pixel area. Reference numeral 103 denotes a contact hole made in the insulating layer.

[0021] Generally, the storage lines STL are fabricated from the same material as that of the gate lines GL and simultaneously with the gate lines GL. The drain electrode SD2 of the thin film transistor TFT is formed as an extension from the drain line DL.

[0022] As shown in FIG. 15, formed on the inner surface of the substrate SUB1 which is also called "the thin film transistor substrate" are the storage line STL, a first insulating layer SiN made preferably of silicon nitride, a second insulating layer PAS made of a passivation layer, and the pixel electrode ITO1, in the order named. The common electrode ITO2 is formed on the inner surface of the other substrate SUB2. A liquid crystal layer LC is sandwiched between the two substrates SUB1 and SUB2.

[0023] Although not shown in FIGS. 14 and 15, orientation films for orientating liquid crystal molecules are disposed on the respective surfaces of the pixel electrodes ITO1 and the common electrode ITO2, are in direct contact with the liquid crystal layer. In the color liquid crystal display element, three-color filters are disposed below the common electrode ITO2 on the substrate SUB2, and in this case, the substrate SUB2 is also called "a color filter substrate."

[0024] In FIG. 15, the storage capacitance C_{STG} shown as a hatched area is formed by the pixel electrode ITO1, the storage line STL, the first insulating layer SiN and the second insulating layer PAS.

[0025] The storage capacitance C_{STG} is determined by the area of the overlap between the pixel electrode ITO1 and the storage line STL, and is therefore determined by the shape and dimensions of the storage line, and consequently, the exact establishment of the storage capacitance C_{STG} is difficult, and also the resistance is increased.

[0026] The common electrode ITO2 also overlies the gate lines GL and the drain lines DL with the liquid crystal layer interposed therebetween, and therefore a large wiring capacitance is formed between the common electrode ITO2 and the drain and gate lines GL, DL, and consequently delay caused by wiring produces brightness grading in a display image.

[0027] FIG. 16 is a schematic cross-sectional view of the liquid crystal display element for explaining a wiring capacitance formed by the gate line GL, and FIG. 17 is a schematic cross-sectional view of the liquid crystal display element for explaining a wiring capacitance formed by the drain line DL. Positioned over the gate line GL are the first insulating layer SiN, the second insulating layer PAS, the liquid crystal layer LC and the common electrode ITO2. Positioned over the drain line DL are the second insulating layer PAS, the liquid crystal layer LC and the common electrode ITO2. Formed between the wiring lines GL, DL and the common electrode ITO2 are wiring capacitances having configurations indicated by broken

lines in FIGS. 16 and 17, respectively.

[0028] The larger the size of the liquid crystal display element, the longer the lengths of the storage lines STL, the gate lines GL and the drain lines DL, and the larger the wiring capacitances, and therefore the so-called wiring delays occur. Consequently, there is a problem in that flicker or brightness grading occurs in a displayed image.

[0029] A voltage supply to the common electrode ITO2 is made via a conductive paste disposed in the vicinity of the sealing member sealing a pair of substrates together along peripheries of a display area of the substrates. The conductive paste is sandwiched between a common-electrode voltage supply line formed on the substrate SUB1 and the common electrode ITO2 formed on the other substrate SUB2.

[0030] FIG. 18 is a schematic plan view of the liquid crystal display element for explaining an example of positions of the conductive pastes for electrically connecting the common-electrode voltage supply line on the substrate SUB1 to the common electrode ITO2 on the substrate SUB2.

[0031] In this liquid crystal display element, the substrates SUB1 and SUB2 are sealed together by placing the substrate SUB2 over the substrate SUB1 with a sealing member SL interposed therebetween along the periphery of the display area AR of the substrates SUB1 and SUB2.

[0032] The common-electrode voltage supply line (not shown) is formed in the vicinity of the sealing member SL on the substrate SUB1. In the sealing operation, the conductive paste CPT is coated to overlie the common-electrode voltage supply line at positions such as corners of the sealing member SL coated on the substrate SUB1, and then the substrate SUB2 is placed over the substrate SUB2 such that the common electrode ITO2 on the inner surface of the substrate SUB2 is electrically connected to the conductive paste CPT to make possible application of a specified voltage to the common electrode ITO2.

[0033] A voltage supply to the storage lines STL is made by connecting a storage-line voltage supply line (not shown) formed in the vicinity of the sealing member SL on the inner surface of the substrate SUB1 to a power supply (a storage-line driving circuit) at one side or both sides of the display area.

[0034] However, there is a problem in that, the longer the storage lines, the larger the resistance and a wiring capacitance, and fluctuations in potentials occur, and consequently, flicker and brightness grading occur in a display and they deteriorate the quality of the display.

[0035] As for a measure against these, the number of the coated conductive pastes can be increased, the coating operation of the conductive pastes requires a lot of time, and as a result, the so-called tact time is increased. In a driving method employing the common-electrode voltage inversion, it is difficult to reduce the number of the points for voltage supply because a signal is supplied to the common electrode.

[0036] US 5 368 915 discloses an active matrix substrate comprising storage capacitors each having an insulating film formed of a single perovskite oxide or a solid solution composed of a plurality of the perovskite oxides. The storage capacitor is composed of the edge portion of a pixel electrode and a projection which is a part of a gate bus and an insulating form interposed therebetween.

[0037] US 6 022 753 discloses a manufacturing method for liquid crystal displays. Under each cell there passes a storage line covered by a gate insulating layer and a passivation layer. The passivation layer has contact holes exposing the drain electrode, the gate pad, the data pad, the storage pad and the storage electrode.

SUMMARY OF THE INVENTION

[0038] It is an object of the present invention to provide a liquid crystal display element capable of eliminating the need for a voltage supply line.

[0039] A liquid crystal display element comprises a pair of substrates; a liquid crystal layer sandwiched (or interposed) between the pair of substrates; a plurality of gate lines disposed on one of the pair of substrates; a plurality of drain lines disposed to be insulated from and intersect the plurality of the gate lines on the one of the pair of substrates; a plurality of thin film transistors disposed in a vicinity of intersections of the plurality of gate lines and the plurality of drain lines; a plurality of pixel electrodes made of transparent conductive material, each of the plurality of pixel electrodes being disposed in an area surrounded by two adjacent ones of the plurality of gate lines and two adjacent ones of the plurality of drain lines, and driven by a corresponding one of the plurality of thin film transistors; a common electrode disposed on another of the pair of substrates to face the plurality of pixel electrodes; a plurality of storage lines disposed below the plurality of pixel electrodes with an insulating layer interposed between the plurality of storage lines and the plurality of pixel electrodes, each of the plurality of pixel electrodes and a portion of the insulating layer thereunder and being formed with an opening in a portion thereof facing a corresponding one of the plurality of storage lines, the opening passing through all thicknesses of the plurality of pixel electrodes and the insulating layer; a plurality of column-like conductive spacers, each of the plurality of column-like conductive spacers disposed in a respective one of the openings for electrically connecting one of the plurality of storage lines to the common electrode.

BRIEF DESCRIPTION OF THE DRAWINGS

[0040] In the accompanying drawings, in which like reference numerals designate similar components throughout the figures, and in which:

FIG. 1 is a plan view of essential parts of a unit pixel

and its vicinity formed on a substrate of a storage type liquid crystal display element according to a first comparative example;

FIG. 2 is a schematic cross-sectional view of the storage type liquid crystal display element taken along line II-II of FIG. 1;

FIG. 3 is a schematic cross-sectional view of a second comparative example of a liquid crystal display element for explaining a wiring capacitance formed by a gate line;

FIG. 4 is a schematic cross-sectional view of the second comparative example for explaining a wiring capacitance formed by a drain line;

FIG. 5 is a plan view of essential parts of a first embodiment of the liquid crystal display element of the present invention for explaining a configuration of its storage line portion;

FIG. 6 is a schematic cross-sectional view of the liquid crystal display element taken along line VI-VI of FIG. 5;

FIG. 7 is a plan view of essential parts of a second embodiment of the liquid crystal display element of the present invention for explaining a configuration of its storage line portion;

FIG. 8 is a schematic cross-sectional view of the liquid crystal display element taken along line VIII-VIII of FIG. 7;

FIG. 9 is a block diagram for explaining an exemplary configuration of a driving system of a general active matrix type liquid crystal display device employing a liquid crystal display element of the present invention;

FIG. 10 is a block diagram showing rough configurations of respective drivers and flows of signals in the liquid crystal display element of FIG. 9;

FIG. 11 is a timing chart showing display data supplied to a display control device from a signal source (a main body) and signals output from the display control device to a drain driver and a gate driver;

FIG. 12 is an external view of a display monitor as an example of electronic equipment incorporating a liquid crystal display device employing a liquid crystal display element of the present invention;

FIG. 13 is an equivalent circuit of a storage type liquid crystal display element;

FIG. 14 is a plan view of essential parts of a unit pixel and its vicinity formed on a substrate of the storage type liquid crystal display element;

FIG. 15 is a schematic cross-sectional view of the storage type liquid crystal display element taken along line XV-XV of FIG. 14;

FIG. 16 is a schematic cross-sectional view of the liquid crystal display element for explaining a wiring capacitance formed by a gate line;

FIG. 17 is a schematic cross-sectional view of the liquid crystal display element for explaining a wiring capacitance formed by a drain line; and

FIG. 18 is a schematic plan view of the liquid crystal

display element for explaining an example of positions of conductive pastes for electrically connecting the common-electrode voltage supply line on one substrate to the common electrode on another substrate.

DETAILED DESCRIPTION

[0041] Now embodiments of the present invention and comparative examples will be described in detail by reference to the drawings.

[0042] FIG. 1 is a plan view of essential parts of a unit pixel and its vicinity formed on a substrate of a storage type liquid crystal display element according to a first comparative example, and FIG. 2 is a schematic cross-sectional view of the storage type liquid crystal display element taken along line II-II of FIG. 1. Reference character ALC denotes an opening, and the same reference characters and numerals as utilized in FIGS. 14 and 15 designate functionally corresponding portions in FIGS. 1 and 2.

[0043] The storage line STL in FIGS. 1 and 2 is formed similarly to that shown in FIGS. 14 and 15. The opening ALC is made at least in the pixel electrode ITO1 overlying the storage line STL. The opening ALC can be made in one or both of the first insulating layer SiN and the second insulating layer PAS overlying the storage line STL in addition to the opening ALC in the pixel electrode ITO1, if necessary.

[0044] It is desirable that the projection of the contours of the opening ALC in the pixel electrode ITO1 on the storage line STL is within the contours of the storage line STL, and it is also desirable that the contours of the openings ALC in the first and second insulating layers SiN, PAS are identical to or within the contours of the opening ALC in the pixel electrode ITO1.

[0045] As in this comparative example, in a case where the storage line STL is provided to divide the area of the pixel electrode ITO1 (or the light-transmissive region of the pixel electrode ITO1 when the light transmission of the storage line STL is lower than that of the pixel electrode ITO1) into at least two parts, fluctuations in light transmission is negligible which is caused by non-uniformity of electric charge distribution in the pixel electrode ITO1 due to presence of the opening ALC, if the opening ALC is made in the pixel electrode ITO1 to have the above-described dimensional relationship.

[0046] By spacing the storage line STL and the pixel electrode ITO1 from each other by at least two kinds of insulating layers (PAS, SiN), if a fault such as a pinhole occur in one of the insulating layers, its adverse effects (for example, a short circuit between the storage line STL and the pixel electrode ITO1) is eliminated by the other of the insulating layers. Consequently, the above openings in the pixel electrode ITO1 or both of the pixel electrode ITO1 and the insulating layers PAS, SiN can be made to have a desired size without concern for possible faults in the insulating layers.

[0047] The opening ALC passes through all the thicknesses of the pixel electrode ITO1, the first insulating layer SiN and the second insulating layer PAS and opposes the storage line STL.

[0048] With this configuration, the storage capacity C_{stg} uses hatched portions of the first and second insulating layers SiN and PAS indicated in FIG. 2 as dielectrics, and is formed between a portion of the pixel electrode ITO1 along the opening ALC in the pixel electrode ITO1 and the storage line STL opposing the portion. The capacitance value of the storage capacitance C_{stg} can be controlled by the size of the opening ALC.

[0049] In the liquid crystal display device of this comparative example, it is desirable that the opening ALC is made in the pixel electrode ITO1 or both of the pixel electrode ITO1 and the insulating layers PAS, SiN in each of pixels contributing to an image display (in other words, pixels within the effective display area).

[0050] Further, in the present comparative example, the capacitance value of the storage capacity C_{stg} of each pixel is capable of being adjusted by the area of the opening ALC, and therefore this eliminates the complicated step for adjusting the size of the storage line STL. Thus, the width of the storage line STL in a direction perpendicular to a direction of extension of the storage line STL does not need to be reduced, and therefore an increase in the resistance of the storage line STL is suppressed. Consequently, electric charges having been stored in the pixel electrode ITO1 during one frame period can be removed from the pixel electrode ITO1 immediately in the next frame period.

[0051] Further, in this comparative example, the capacitance value of the storage capacitance C_{stg} can also be established by controlling the size of the opening ALC made in the pixel electrode ITO1 for each pixel such that there is little variation in capacitance value of the storage capacitance from pixel to pixel, and consequently, occurrence of a non-uniformity display and flicker due to variations in the storage capacitance C_{stg} can be prevented.

[0052] FIG. 3 is a schematic cross-sectional view of a second comparative example of a liquid crystal display element for explaining a wiring capacitance formed by the gate line GL, and FIG. 4 is a schematic cross-sectional view of the second comparative example for explaining a wiring capacitance formed by the drain line DL. In FIGS. 3 and 4, reference character CUT denotes cut-outs made in the common electrode ITO2 formed on the substrate SUB2. The same reference characters and numerals as utilized in FIGS. 14 and 15 designate functionally corresponding portions in FIGS. 3 and 4.

[0053] In this comparative example, the wiring capacitances formed between the gate line GL and the common electrode ITO2 and the wiring capacitance formed between the drain line DL and the common electrode ITO2 can be reduced to approximately zero, and as a result, time delay due to wiring is reduced and occurrence of flicker and brightness grading in a display can be prevented.

[0054] FIG. 5 is a plan view of essential parts of a first embodiment of the liquid crystal display element of the present invention for explaining a configuration of its storage line STL portion, and FIG. 6 is a schematic cross-sectional view of the liquid crystal display element taken along line VI-VI of FIG. 5. In FIGS. 5 and 6, reference character SOC denotes a conductive column-like spacer, SH is a light-shielding member, and the same reference characters and numerals as utilized in FIGS. 1-4 designate functionally corresponding portions in FIGS. 5 and 6.

[0055] The conductive column-like spacer SOC is shaped from a photosensitive resin having carbon black dispersed therein or a conductive polymer, for example. For the former, a material capable of being hardened by photolithography is suitable for the photosensitive resin. For the latter, for example, the conductive polymer may be a material belonging to poly-acetylene system, poly-phenylene system, etc. mixed with dopants such as an arsenic compound AsF_5 , sulfuric acid H_2SO_4 and iodine I_2 and a trace amount of a photoinitiator, or a heterocyclic polymer such as poly-pyrol, or an ionic polymer such as aromatic amine series. Functional groups of these materials may be modified so that their polymerization starts with irradiation of light such as ultraviolet light.

[0056] In this embodiment, an opening ALCN is made in the first insulating layer SiN, the second insulating layer PAS and the pixel electrode ITO1 formed over the storage line STL formed on the substrate SUB1, and a conductive column-like spacer SOC is disposed in the opening ALCN to electrically connect the storage line STL to the common electrode ITO2 on the other substrate SUB2.

[0057] This configuration eliminates the need for a voltage supply line for the storage line STL, and provision of the conductive column-like spacer SOC in each pixel prevents the brightness grading and flicker because the number of its voltage supply points is plural and as a result time delay due to wiring does not occur if the wiring length of the storage line STL is increased.

[0058] In FIGS. 5 and 6, the opening ALCN is such that the area of the opening in the pixel electrode ITO1 is larger than that of the opening in the underlying insulating layers PAS and SiN, and the reason for this is that fabrication of the conductive column-like spacer SOC is facilitated. There is no problem if the area of the opening in the pixel electrode ITO1 is made identical with that of the opening in the insulating layers PAS and SiN as in the case of FIGS. 1 and 2.

[0059] In FIG. 5, a contour of an opening of a black matrix BM formed on the other substrate SUB2 is indicated by broken lines for the purpose of reference.

[0060] FIG. 7 is a plan view of essential parts of a second embodiment of the liquid crystal display element of the present invention for explaining a configuration of its storage line STL portion, and FIG. 8 is a schematic cross-sectional view of the liquid crystal display element taken along line VIII-VIII of FIG. 7. In FIGS. 7 and 8, reference character ITO3 denotes a conductive layer, and the same

reference characters and numerals as utilized in FIGS. 1-6 designate functionally corresponding portions in FIGS. 7 and 8.

[0061] In this embodiment, the conductive layer ITO3 is formed to cover the storage line STL at the bottom of the opening ALCN in Embodiment 1, and the conductive column-like spacer SOC is formed on the conductive layer ITO3.

[0062] The configuration of this embodiment prevents corrosion of the otherwise storage line STL, and thereby provides stable display characteristics for a long period of time in addition to the advantage provided by Embodiment 1.

[0063] Next, Embodiment 3 of the present invention will be explained.

[0064] In this embodiment, a second type conductive column-like spacer is used instead of the conductive paste CPT disposed in the vicinity of the sealing member SL in FIG. 8. The second type column-like spacer is similar in shape to the above-explained conductive column-like spacer (hereinafter the first column-like spacer) disposed in the pixel area, but is made to have a required area in cross section. This embodiment makes possible a voltage supply to the common electrode ITO2 without using the conductive paste, and reduces the number of manufacturing steps considerably by fabricating the second type column-like spacer simultaneously with the first type column-like spacers.

[0065] The following explains an example of a liquid crystal display device employing a liquid crystal display element of the present invention, in respect of a configuration of its driving circuit and application of the liquid crystal display device.

[0066] FIG. 9 is a block diagram for explaining an exemplary configuration of a driving system of a general active matrix type liquid crystal display device employing a liquid crystal display element of the present invention.

[0067] The liquid crystal display device includes: a liquid crystal display element PNL having a liquid crystal layer sandwiched between a pair of substrates; a circuit (IC chips) disposed at the periphery of the liquid crystal display element PNL for driving drain lines (also called data lines, drain signal lines or video signal lines), that is, the above-described drain driver DDR; a circuit (IC chips) disposed at the periphery of the liquid crystal display element PNL for driving gate lines (also called gate signal lines or scanning signal lines), that is, the above-described gate driver GDR; a display control device CRL serving as a display control means for supplying display data for an image display, clock signals and gray scale voltages to the drain driver DDR and the gate driver GDR; and a power supply circuit PWU. The display control device CRL is supplied with display data (the above-mentioned display signals) from external signal sources such as computers, personal computers, and TV receiver circuits, control signal clocks, display timing signals and syn signals.

[0068] The display control device CRL includes a gray-

scale reference voltage generating section, a timing converter TCON and others, and converts the display data from the external source into data in format appropriate for a display on the liquid crystal display element PNL.

[0069] The display signals and clock signals for the gate driver GDR and the drain driver DDR are supplied as indicated in FIG. 9. A carry signal output from one stage of the drain driver DDR is given to a carry input of the next stage of the drain driver DDR.

[0070] A plurality of storage lines STL are disposed in parallel with the gate lines GL in the display area of the liquid crystal display element PNL. The storage lines STL are connected to the common electrode via the conductive column-like spacers explained in the above embodiments, and are supplied with a specified voltage from the power supply circuit PWU.

[0071] FIG. 10 is a block diagram showing rough configurations of the respective drivers and flows of the signals in the liquid crystal display element of FIG. 9. The

drain driver DDR comprises a data latch section for display data (display signals) such as video (picture) signals and an output-voltage generating circuit. There are a gray-scale reference voltage generating section HTV, a multiplexer MPX, a common-electrode voltage generating section CVD, a common-electrode driver CDD, a level shift circuit LST, a gate-on voltage generating section GOV, a gate-off voltage generating section GFD, and a DC-DC converter D/D mounted on a board mounting the display control device CRL and the power supply circuit PWU shown in FIG. 9.

[0072] FIG. 11 is a timing chart showing display data supplied to the display control device CRL from a signal source (a main body) and signals output from the display control device CRL to the drain driver DDR and the gate driver GDR. The display control device CRL receives the control signals (the clock signals, display timing signals and syn signals) from the signal source and generates a clock D1 (CL1), a shift clock D2 (CL2) and display data as control signals for the drain driver DDR, and at the same generates a frame start command signal FLM, a clock G (CL3) and display data as control signals for the gate driver GDR.

[0073] Incidentally, in the case of a system of using low-voltage difference signals (LVDS signals) for transfer of display data from the signal source, the LVDS signals from the signal source are converted into original signals by an LVDS receiving circuit mounted on the board (the interface board) mounting the display control device CRL, and then are supplied to the gate driver GDR and the drain driver DDR.

[0074] As is apparent from FIG. 11, the frequency of the shift clock signal D2 (CL2) for the drain driver DDR is the same as that of a clock signal (DCLK) supplied from the main computer or the like and display data, and is a high frequency of about 40 MHz in the case of an XGA liquid crystal display element. The liquid crystal display device of such a configuration has a feature of a thin profile and low power consumption and tends to be widely

used as a display device in various fields in the future.

[0075] FIG. 12 is an external view of a display monitor as an example of electronic equipment incorporating a liquid crystal display device employing the liquid crystal display element of the present invention. The liquid crystal display device is used as a display section of the display monitor.

[0076] The liquid crystal display element PNL constituting the liquid crystal display device of the display monitor has the storage lines and the conductive column-like spacers of the configuration explained in the above embodiments, has a storage capacitance appropriately established for each pixel, has wiring capacitances reduced, and is capable of providing a display free from occurrence of flicker and uniform in brightness over the entire display area with brightness grading eliminated.

[0077] It is needless to say that application of the liquid crystal display element of the present invention is not limited to such a display monitor, but the liquid crystal display element of the present invention can be used as a monitor of a desk-top personal computer and a display device of a notebook personal computer, a TV receiver, and other equipment.

[0078] As explained above, in the present invention, the storage capacitance formed by the storage line can be controlled by providing an opening in a pixel electrode, wiring capacitances of the gate lines and the drain lines are reduced by providing cutouts in the common electrode over the gate and drain lines, and manufacturing tact can be improved by disposing conductive column-like spacers between the common electrode and the storage lines such that voltage supply to the common electrode and the storage lines can be made without using any conductive pastes or by using the minimum number of the conductive pastes, and consequently, the present invention provides the high-quality liquid crystal display element.

Claims

1. A liquid crystal display element comprising:

a pair of substrates (SUB1, SUB2);
 a liquid crystal layer (LC) sandwiched between said pair of substrates;
 a plurality of gate lines (GL) disposed on one of said pair of substrates;
 a plurality of drain lines (DL) disposed to be insulated from and intersected by said plurality of said gate lines on said one of said pair of substrates;
 a plurality of thin film transistors (TFT) disposed in a vicinity of intersections of said plurality of gate lines and said plurality of drain lines;
 a plurality of pixel electrodes (ITO1) made of transparent conductive material, each of said plurality of pixel electrodes being disposed in an

area surrounded by two adjacent ones of said plurality of gate lines and two adjacent ones of said plurality of drain lines, and driven by a corresponding one of said plurality of thin film transistors;

a common electrode (ITO2) disposed on the other of said pair of substrates to face said plurality of pixel electrodes; and
 a plurality of storage lines (STL) disposed below said plurality of pixel electrodes with an insulating layer (PAS, SiN) interposed between said plurality of storage lines and said plurality of pixel electrodes,

characterized in that

each of said plurality of pixel electrodes is formed with an opening (ALC) in a portion thereof facing a corresponding one of said plurality of storage lines, a portion of said insulating layer (SiN, PAS) under the pixel electrode is also formed with an opening (ALCN), and

a plurality of column-like conductive spacers (SOC) are provided, each of said plurality of column-like conductive spacers being disposed in a respective one of said openings for electrically connecting one of said plurality of storage lines to said common electrode.

2. A liquid crystal display element according to claim 1, wherein the contour of the opening (ALC) in the pixel electrode (ITO1) is within the contour of the storage line (STL).
3. A liquid crystal display element according to one of the preceding claims, wherein the insulating layer (PAS, SiN) comprises a first insulating layer (SiN) and a second insulating layer (PAS) overlaying the storage line (STL) in this order.
4. A liquid crystal display element according to claim 2, wherein the contour of the opening (ALC) in the insulating layer (SiN, PAS) is within the contour of the opening in the pixel electrode ITO1 (STL).

Patentansprüche

1. Flüssigkristallanzeigeelement mit:

zwei Substraten (SUB1, SUB2);
 einer zwischen den zwei Substraten eingeschlossenen Flüssigkristallschicht (LC);
 mehreren Gate-Leitungen (GL) auf einem der zwei Substrate; mehreren Drain-Leitungen (DL), die so auf dem einen der zwei Substrate angebracht sind, dass sie gegen die Gate-Leitungen isoliert sind und diese schneiden; mehreren Dünnschichttransistoren (TFT) in der Nähe

he der Schnittpunkte der mehreren Gate-Leitungen und der mehreren Drain-Leitungen; mehreren Pixel-Elektroden (ITO1) aus transparentem, leitendem Material, wobei jede der Pixel-Elektroden in einem Bereich angebracht ist, der von zwei benachbarten Gate-Leitungen und zwei benachbarten Drain-Leitungen umgeben ist, und von einem entsprechendem Dünngleichtransistor angesteuert wird; einer gemeinsamen Elektrode (ITO2) auf dem anderen der zwei Substrate gegenüber den Pixel-Elektroden; und mehreren Speicherleitungen (STL) unter den Pixel-Elektroden mit einer Isolierschicht (PAS, SiN) zwischen den Speicherleitungen und den Pixel-Elektroden,

dadurch gekennzeichnet, dass

jede der Pixel-Elektroden mit einer Öffnung (ALC) in einem Bereich derselben gegenüber der entsprechenden Speicherleitung versehen ist, ein Bereich der isolierenden Schicht (SiN, PAS) unter der Pixel-Elektrode auch mit einer Öffnung (ALCN) versehen ist, und mehrere säulenartige leitende Abstandshalter (SOC) vorgesehen sind, wobei jeder der säulenartigen leitenden Abstandshalter in einer jeweiligen Öffnung angeordnet ist, um eine der Speicherleitungen mit der gemeinsamen Elektrode zu verbinden.

2. Flüssigkristallanzeigeelement nach Anspruch 1, bei dem die Kontur der Öffnung (ALC) in der Pixel-Elektrode (ITO1) innerhalb der Kontur der Speicherleitung (STL) liegt.
3. Flüssigkristallanzeigeelement nach einem der vorherigen Ansprüche, bei dem die Isolierschicht (PAS, SiN) eine erste Isolierschicht (SiN) und eine zweite Isolierschicht (PAS) über der Speicherleitung (SCL) in dieser Reihenfolge aufweist.
4. Flüssigkristallanzeigeelement nach Anspruch 2, bei dem die Kontur der Öffnung (ALC) in der Isolierschicht (SiN, PAS) innerhalb der Kontur der Öffnung in der Pixel-Elektrode (ITO1) ist.

Revendications

1. Un élément d'affichage à cristal liquide comprenant : une paire de substrats (SUB1, SUB2) ; une couche de cristal liquide (LC) prise en sandwich entre ladite paire de substrats ; une pluralité de lignes de grilles (GL) disposées sur l'un de ladite paire de substrats ; une pluralité de lignes de drains (DL) disposées pour être isolées de et croisées par ladite plu-
5. ralité de lignes de grilles sur l'un de ladite paire de substrats ; une pluralité de transistors à couche mince (TFT) disposés à proximité des intersections de ladite pluralité de lignes de grilles et de ladite pluralité de lignes de drains ; une pluralité d'électrodes de pixels (ITO1) constituées d'un matériau conducteur transparent, chacune de ladite pluralité d'électrodes de pixels étant disposée dans une zone entourée par deux lignes de grilles adjacentes parmi ladite pluralité de lignes de grilles et par deux lignes de drains adjacentes parmi ladite pluralité de lignes de drains, et commandée par un transistor correspondant parmi la pluralité de transistors à couche mince ; une électrode commune (ITO2) disposée sur l'autre substrat de ladite paire de substrats pour faire face à ladite pluralité d'électrodes de pixels ; et une pluralité de lignes de stockage (STL) disposées en dessous de ladite pluralité d'électrodes de pixels avec une couche isolante (PAS, SiN) interposée entre ladite pluralité de lignes de stockage et ladite pluralité d'électrodes de pixels,
30. **caractérisé en ce que** chacune de ladite pluralité d'électrodes de pixels est formée avec une ouverture (ALC) dans une partie de celle-ci faisant face à une ligne de stockage correspondante parmi ladite pluralité de lignes de stockage, une partie de ladite couche isolante (SiN, PAS) sous l'électrode de pixel est également formée avec une ouverture (ALCN), et une pluralité d'entretoises conductrices en forme de colonne (SOC) est fournie, chacune de ladite pluralité d'entretoises conductrices en forme de colonne étant disposée dans une ouverture respective parmi lesdites ouvertures pour connecter électriquement l'une de ladite pluralité de lignes de stockage à ladite électrode commune.
35. 2. Un élément d'affichage à cristal liquide selon la revendication 1, dans lequel le contour de l'ouverture (ALC) dans l'électrode de pixel (ITO1) se trouve à l'intérieur du contour de la ligne de stockage (STL).
40. 3. Un élément d'affichage à cristal liquide selon l'une des revendications précédentes, dans lequel la couche isolante (PAS, SiN) comprend une première couche isolante (SiN) et une seconde couche isolante (PAS) recouvrant la ligne de stockage (STL) dans cet ordre.
45. 4. Un élément d'affichage à cristal liquide selon la revendication 2, dans lequel le contour de l'ouverture

(ALC) dans la couche isolante (SIN, PAS) se trouve
à l'intérieur du contour de l'ouverture dans l'électrode
de pixel ITO1 (STL).

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FIG. 1

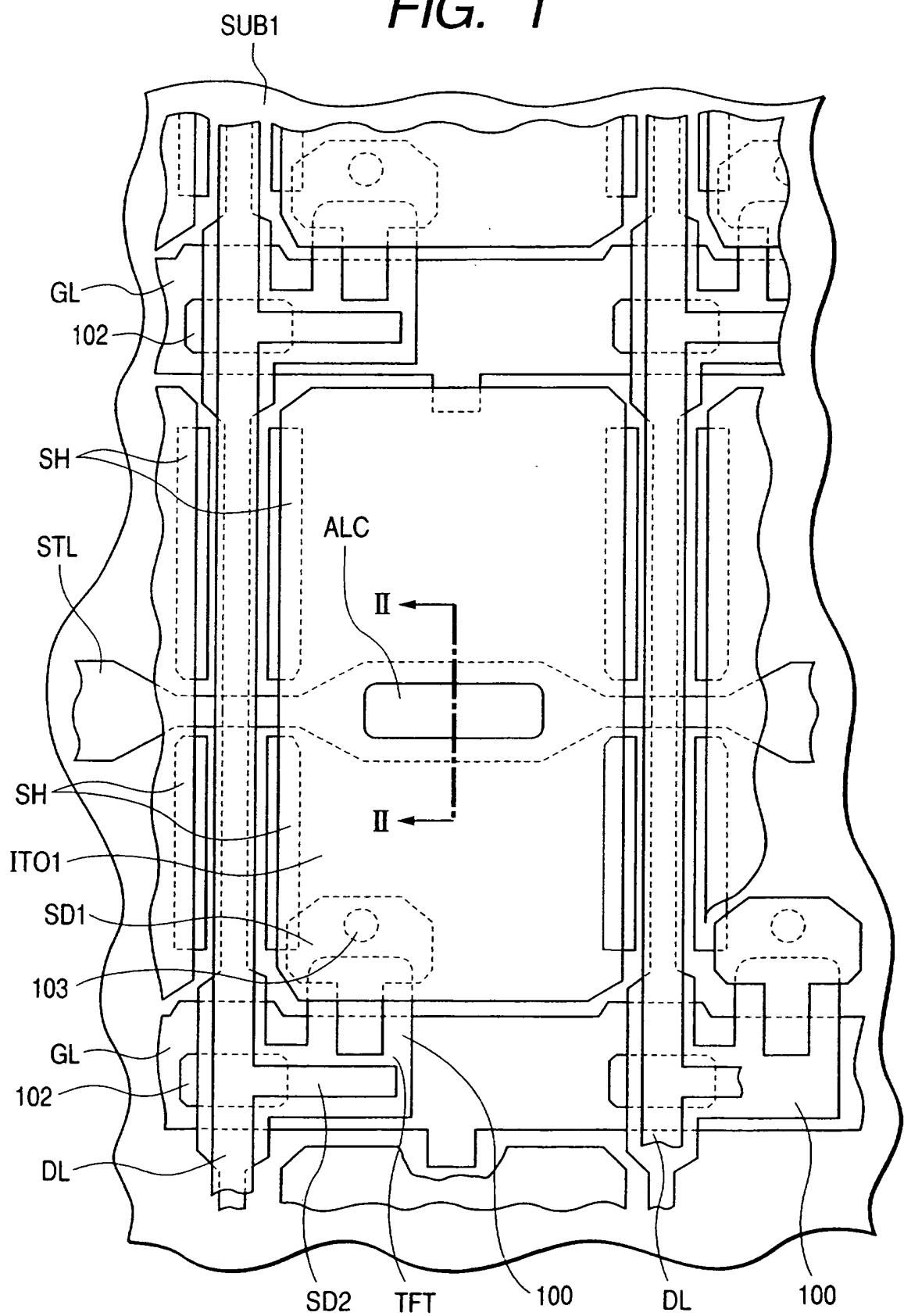


FIG. 2

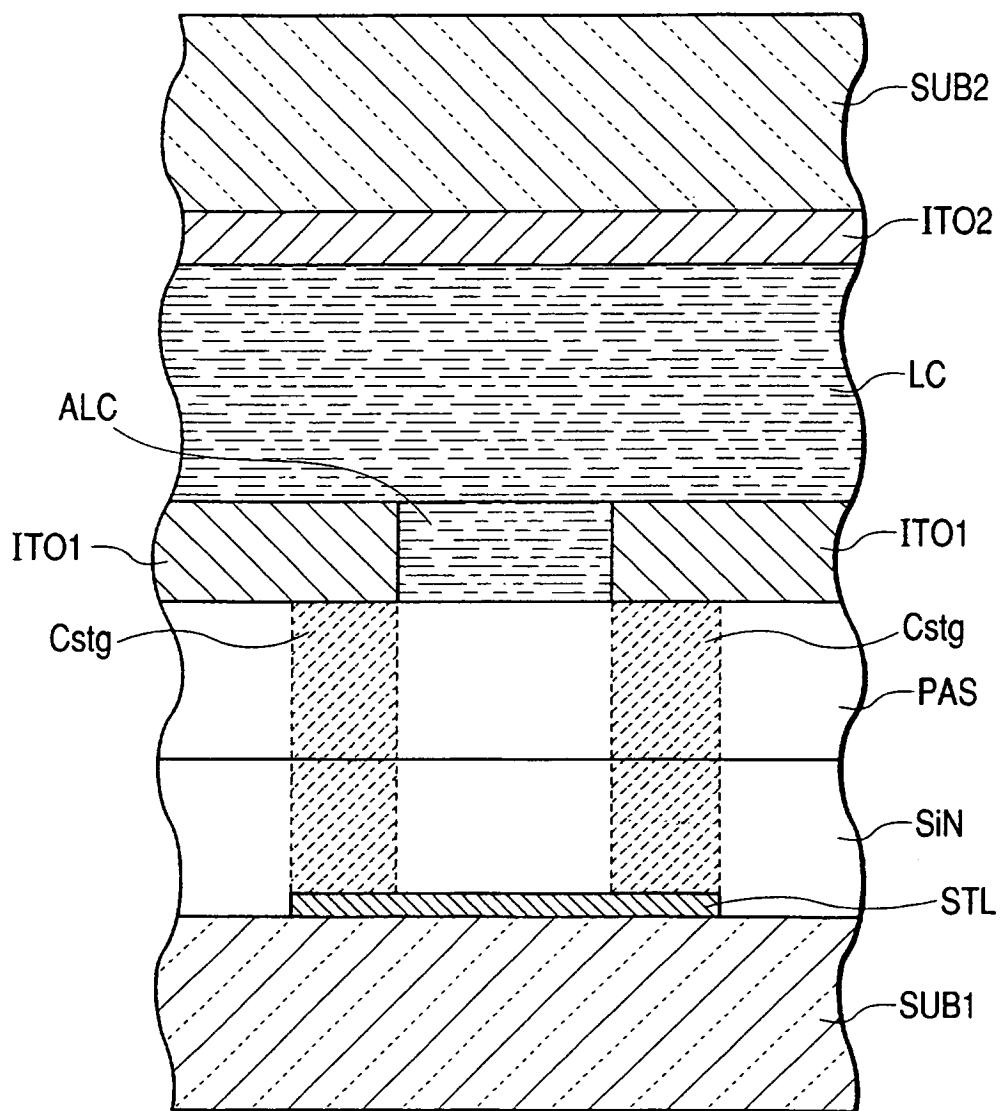


FIG. 3

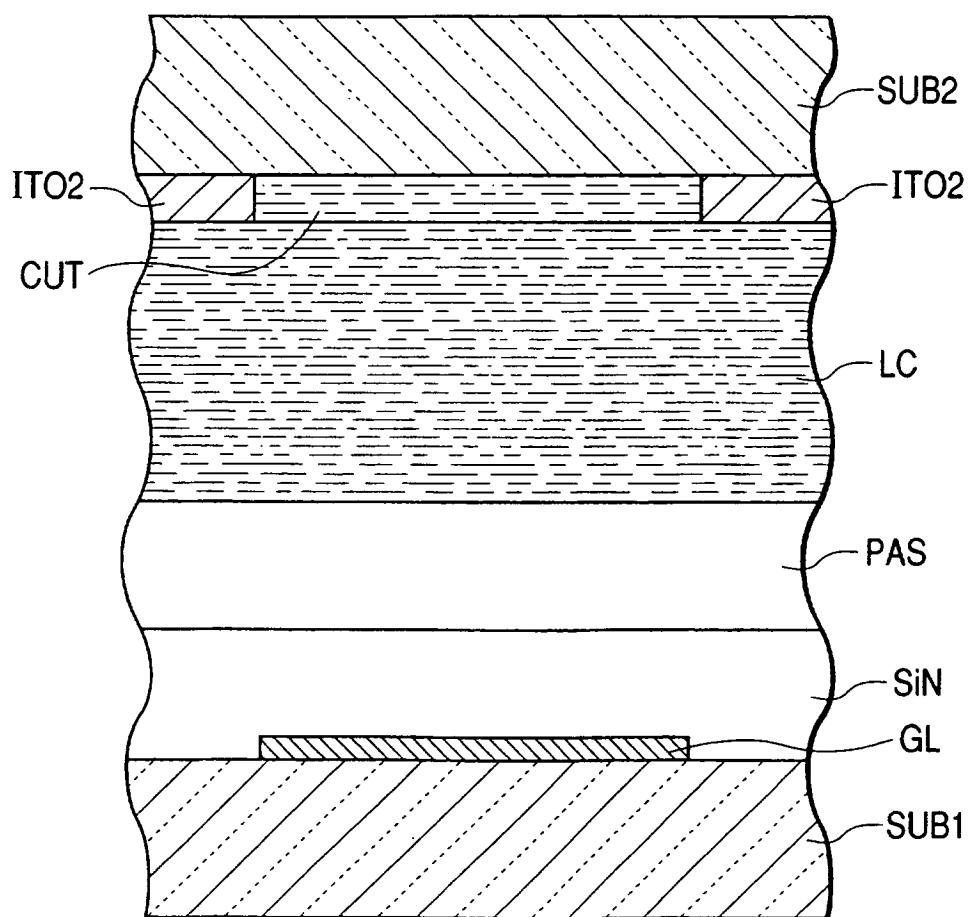


FIG. 4

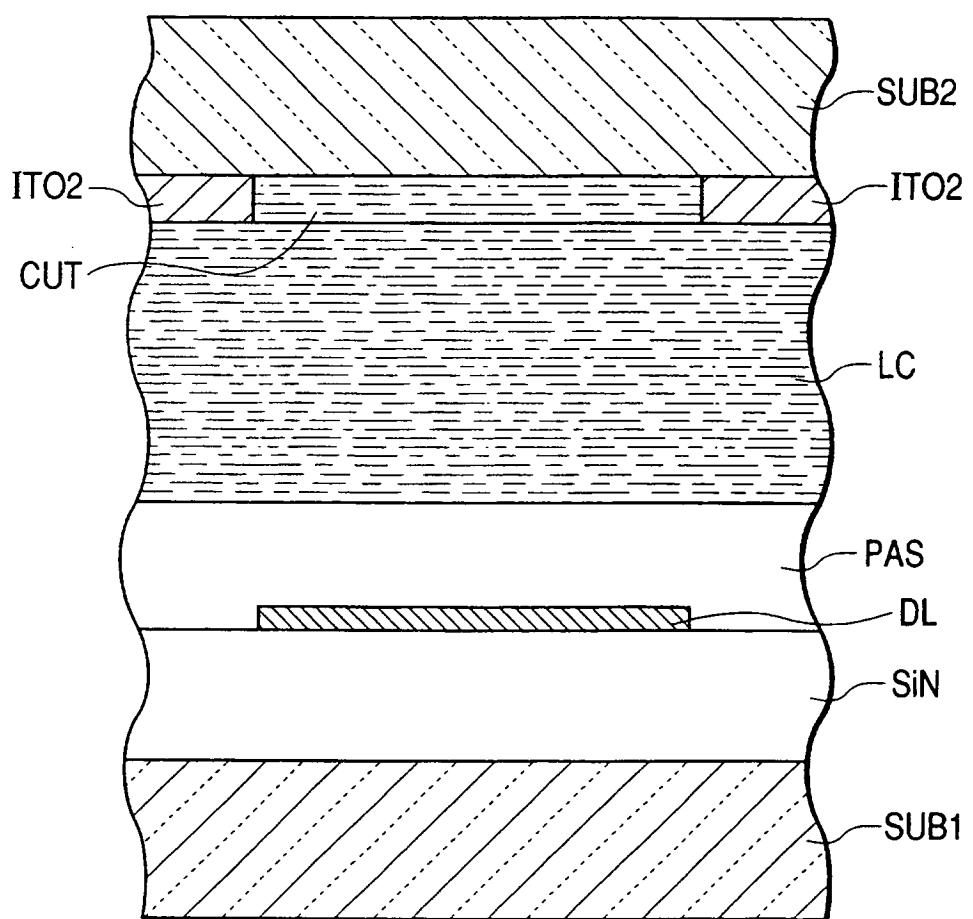


FIG. 5

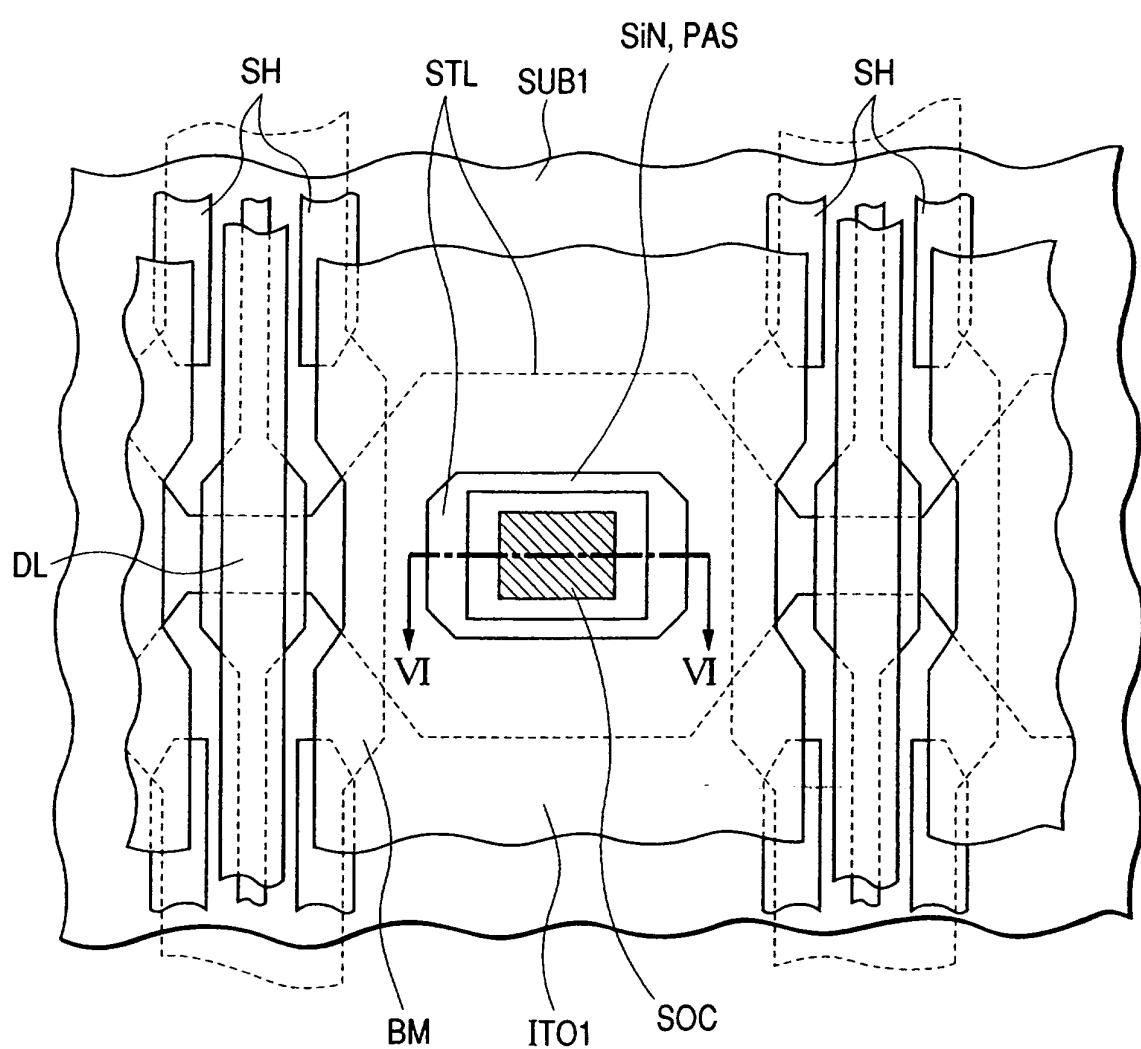


FIG. 6

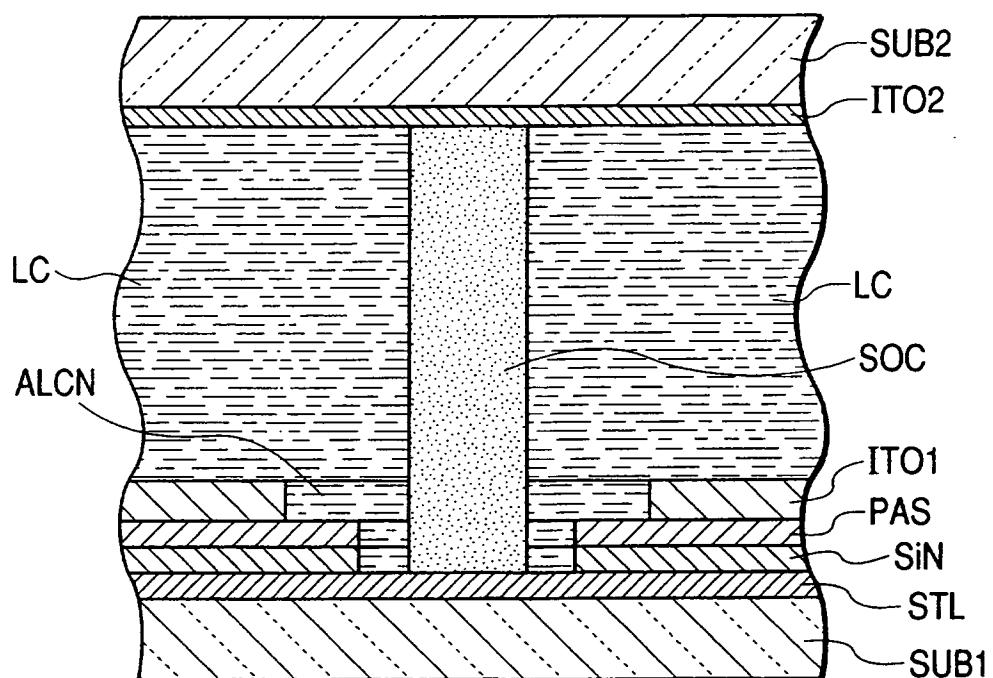


FIG. 7

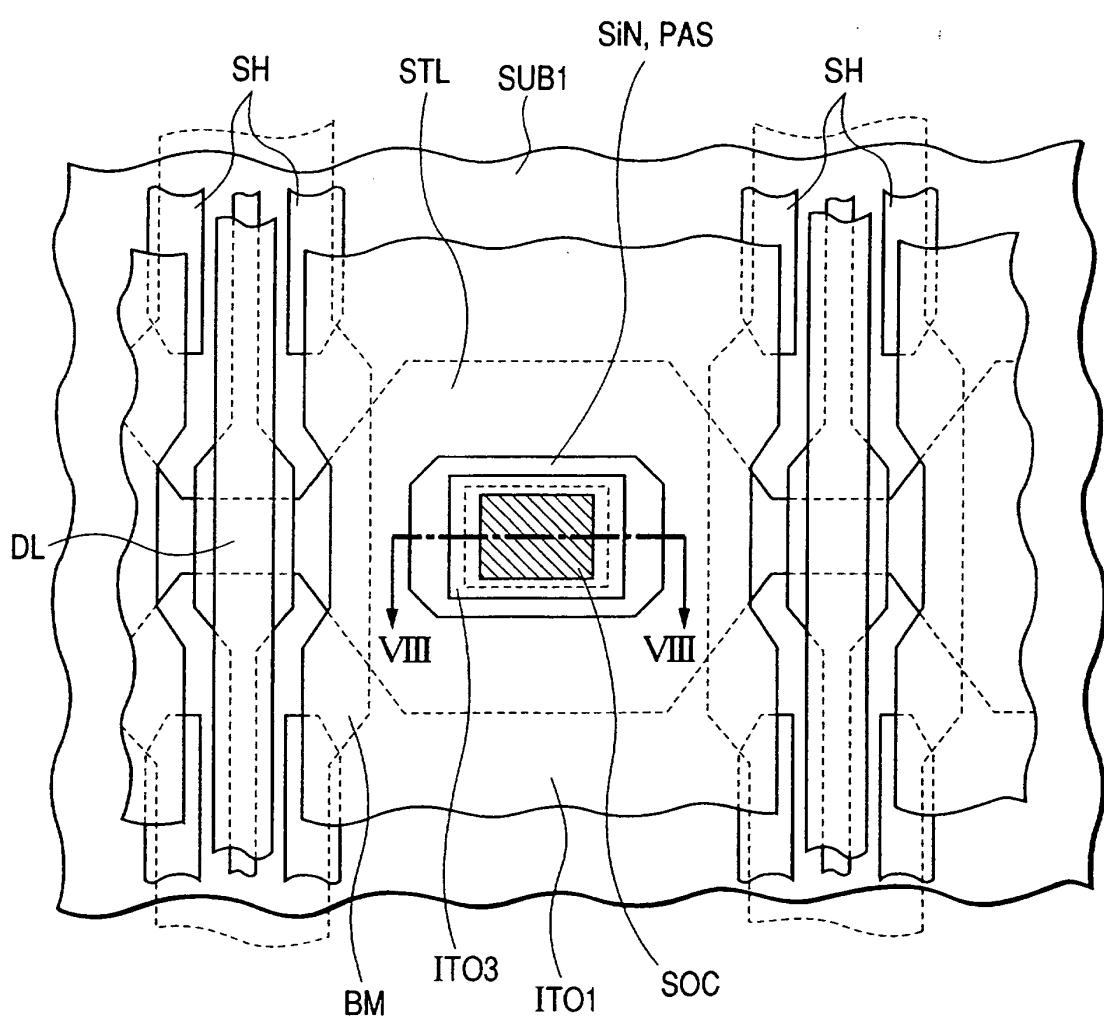


FIG. 8

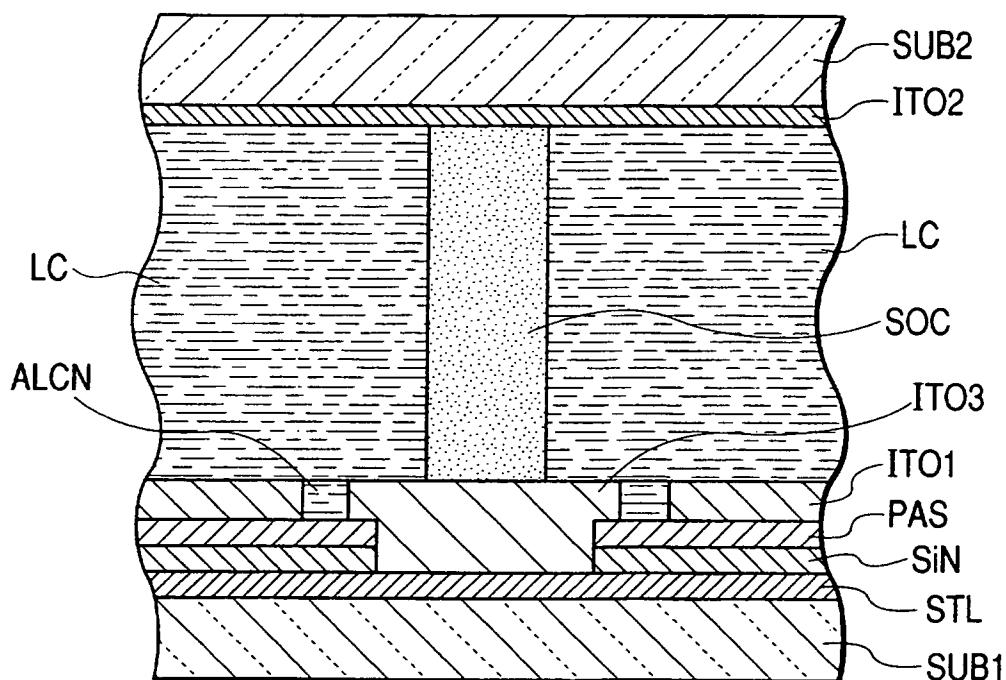


FIG. 9

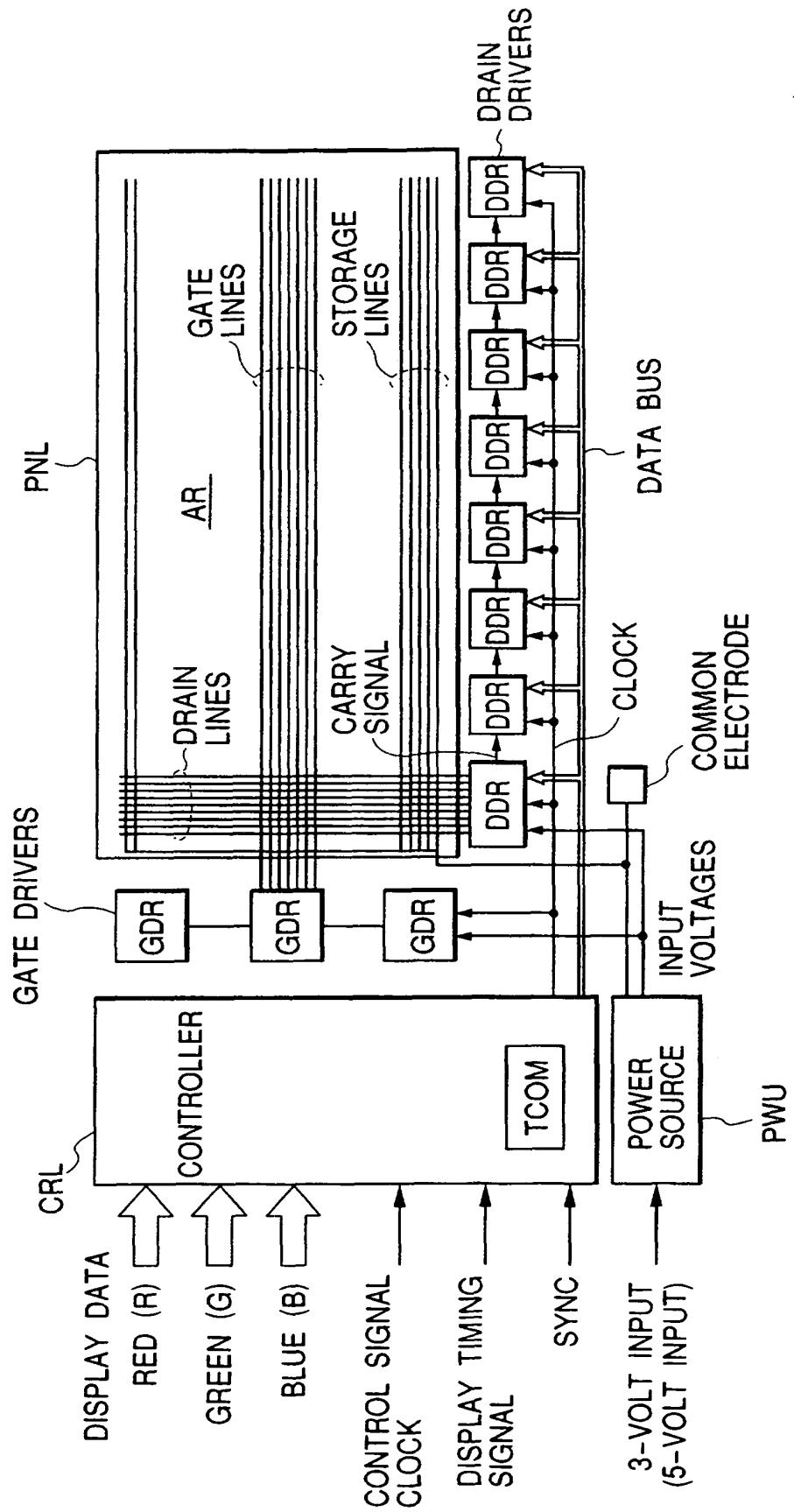


FIG. 10

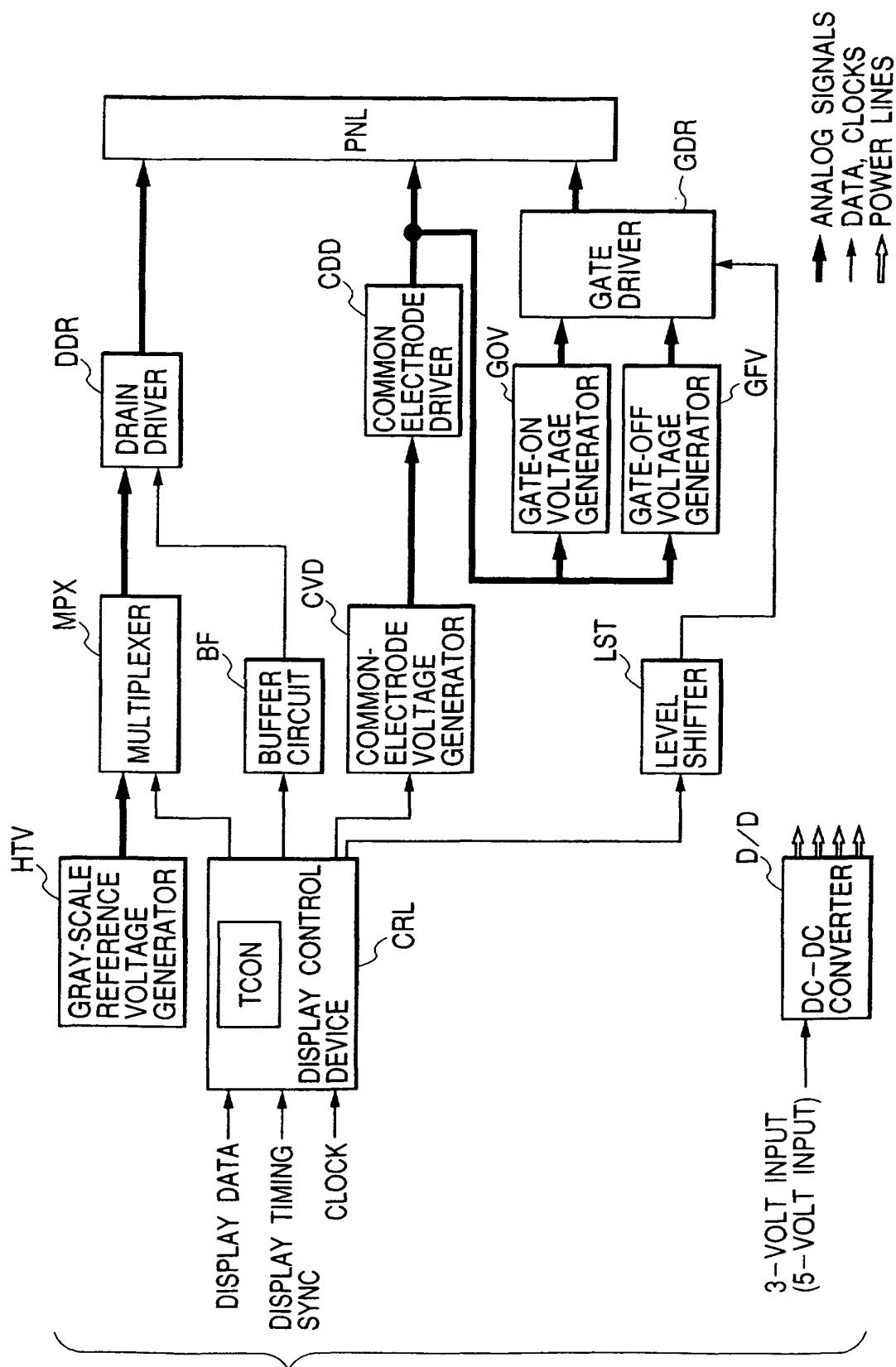


FIG. 11

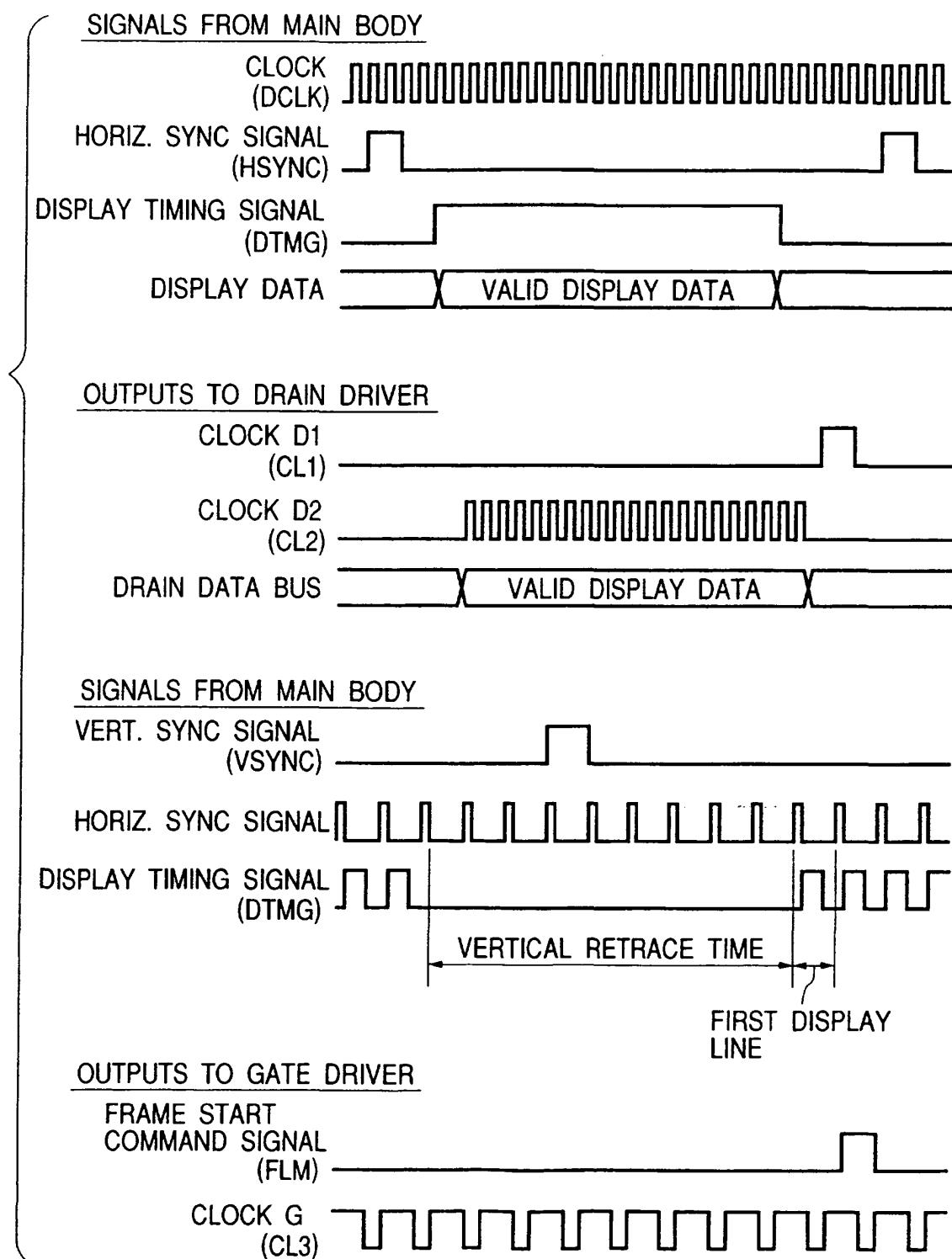


FIG. 12

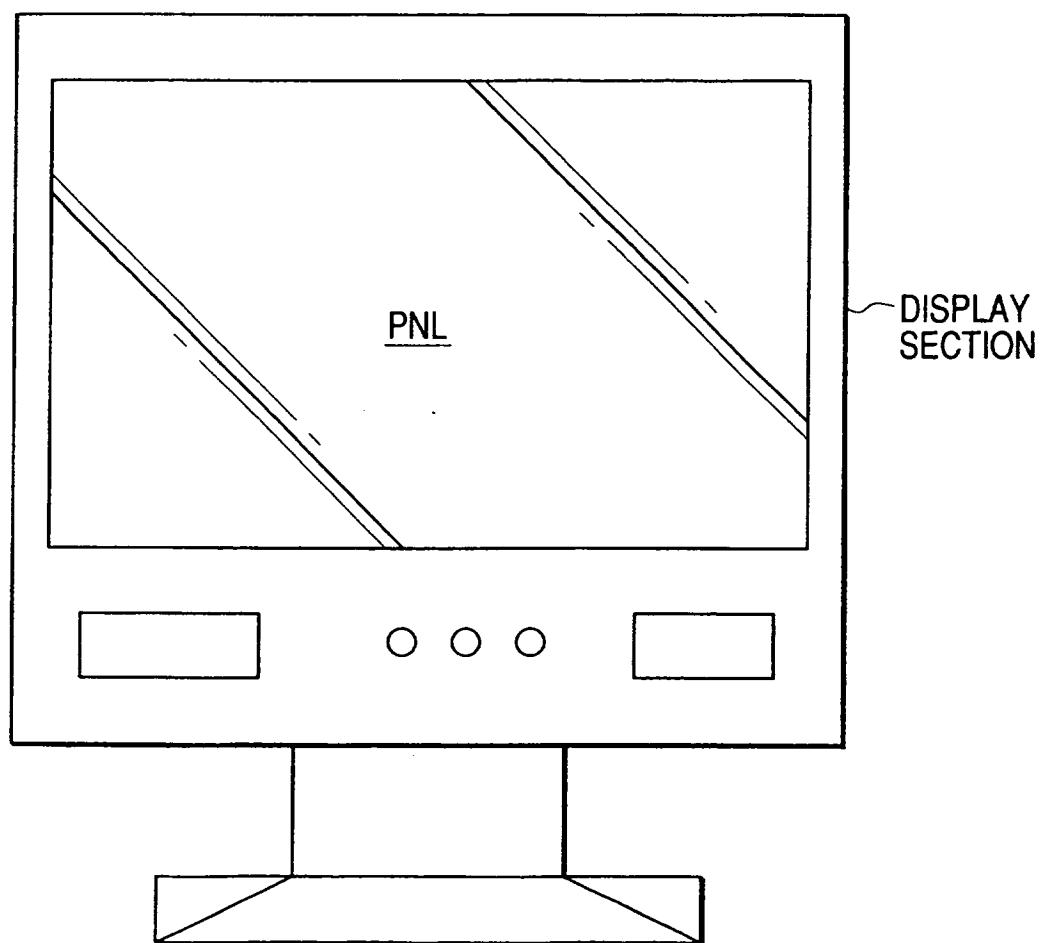


FIG. 13

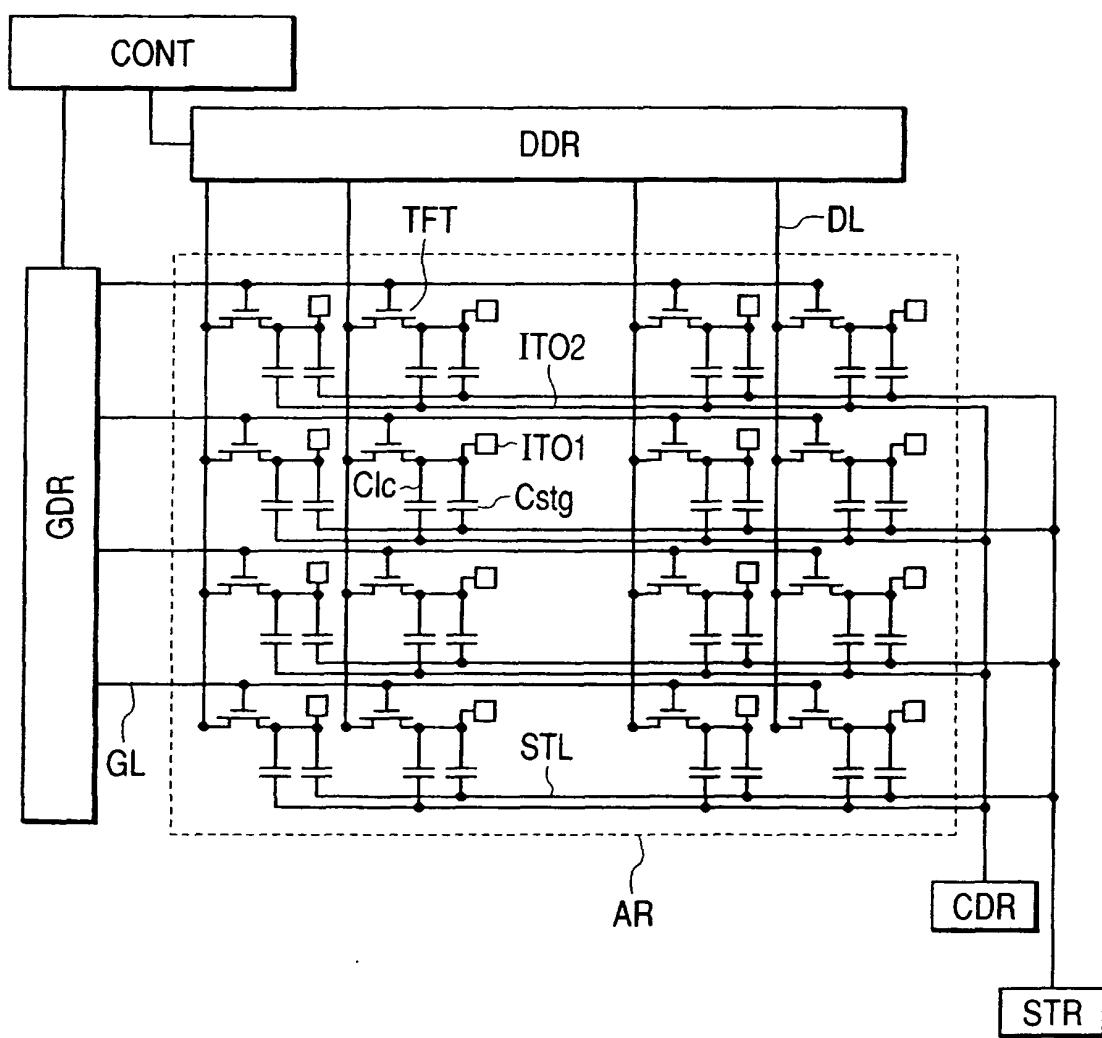


FIG. 14

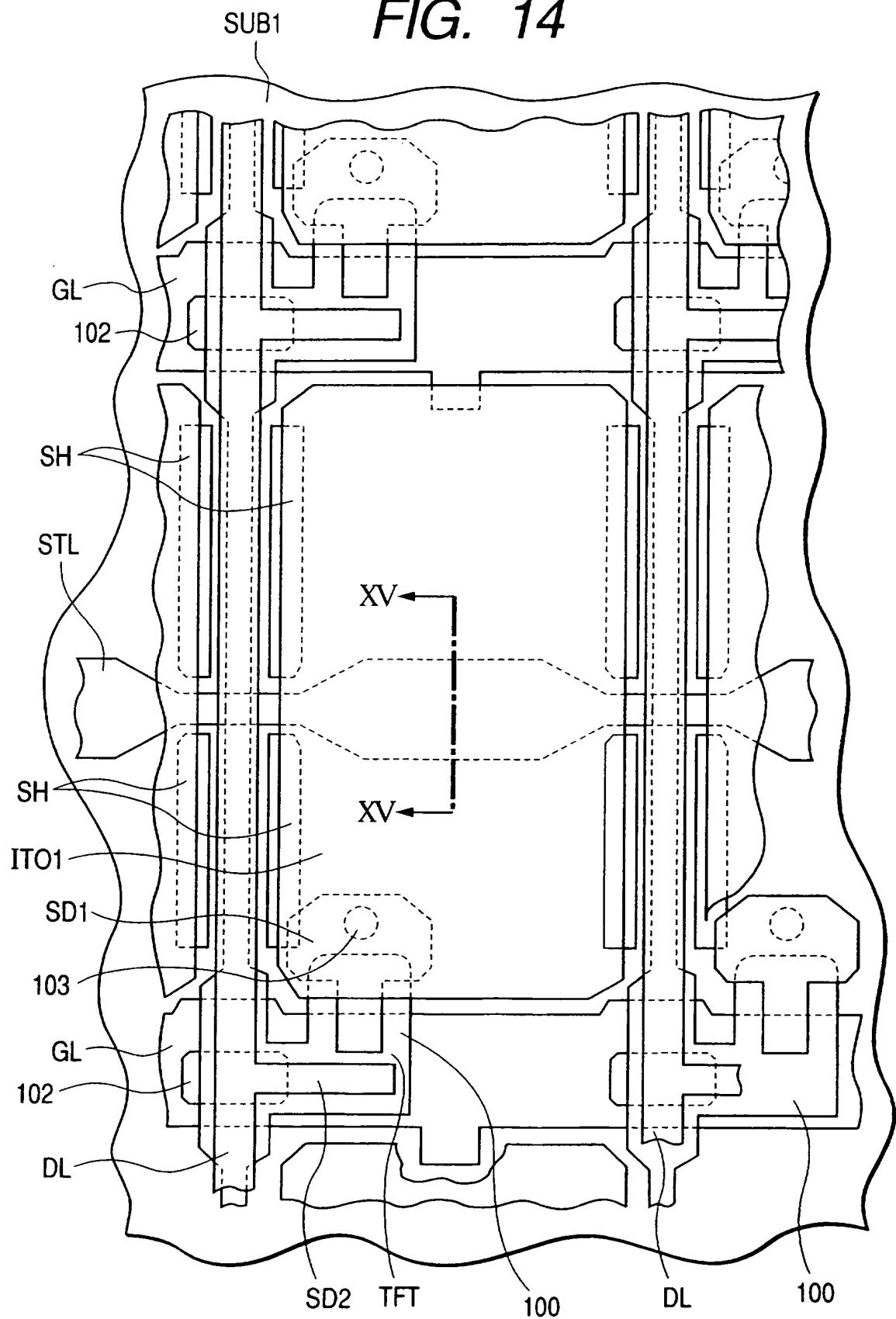


FIG. 15

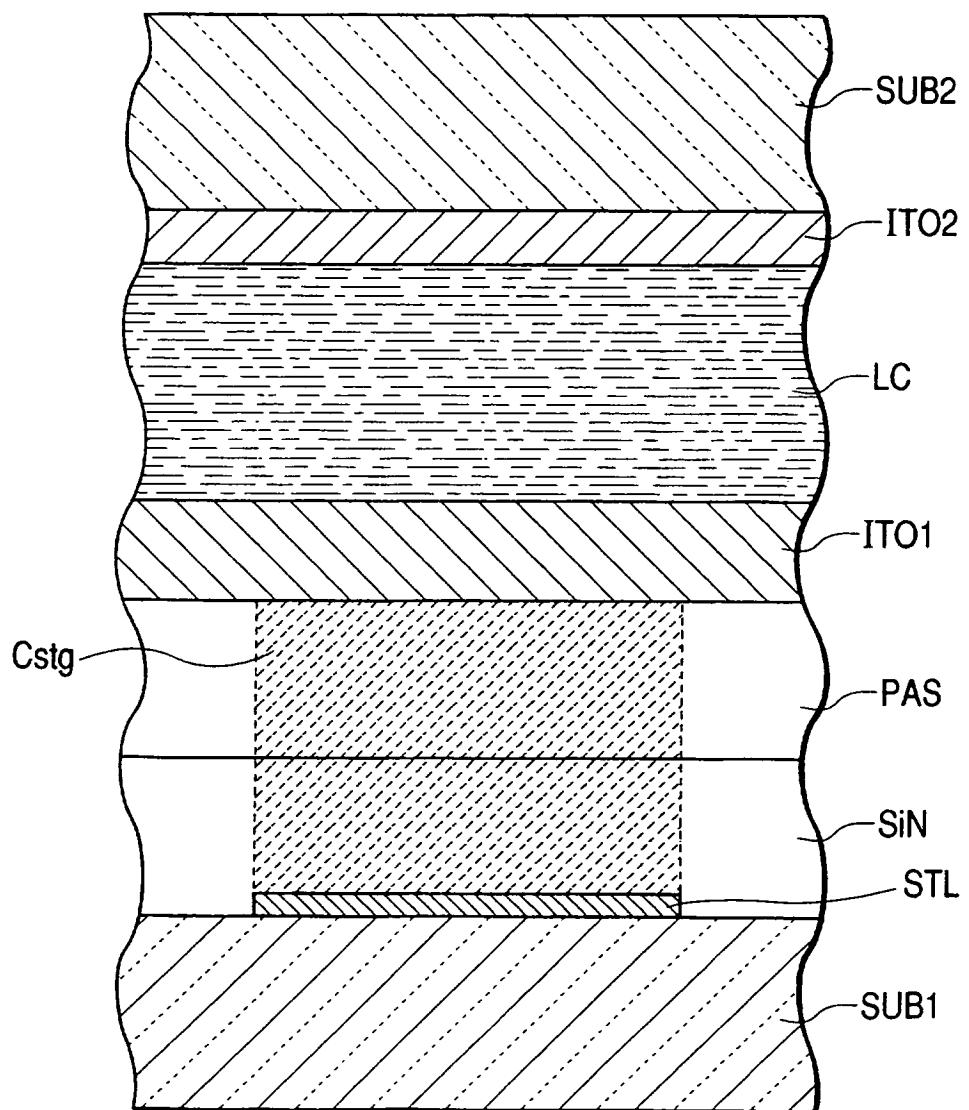


FIG. 16

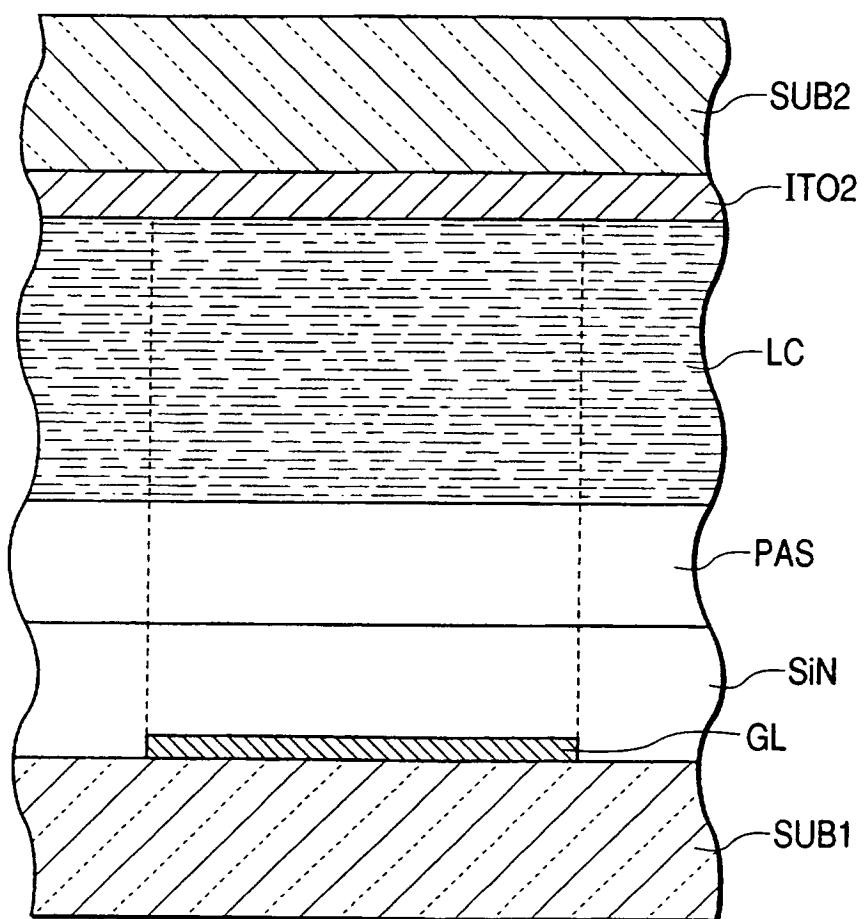


FIG. 17

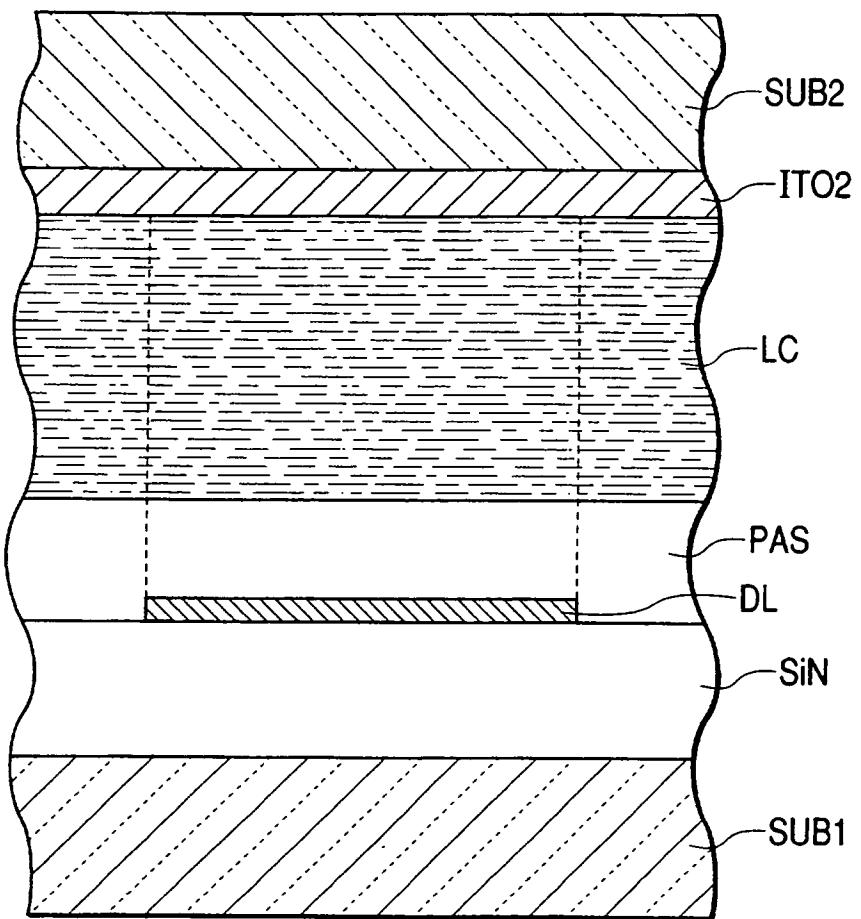
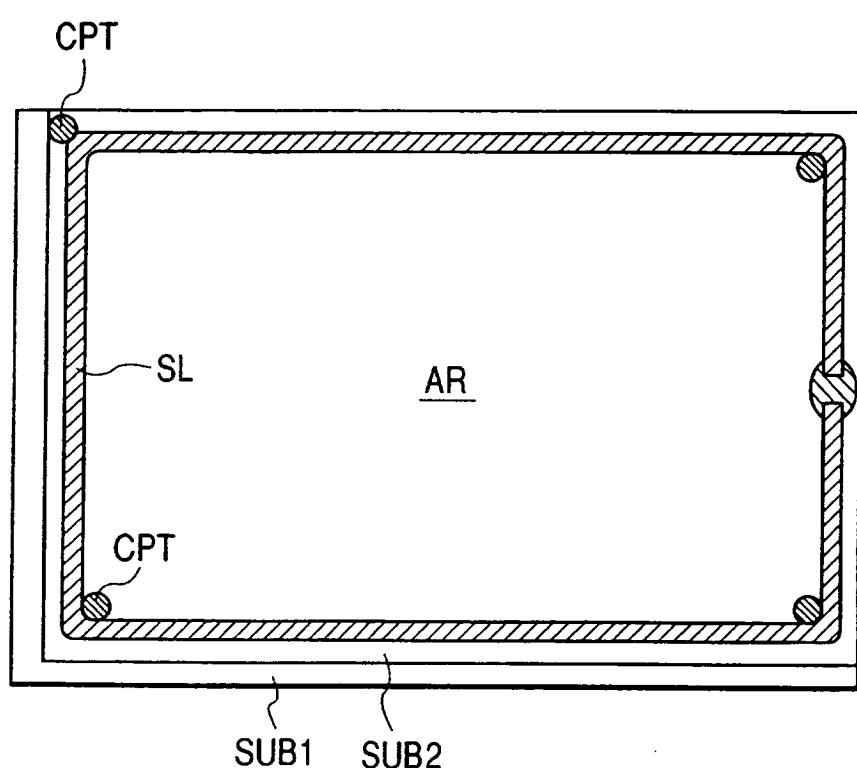


FIG. 18



专利名称(译)	具有受控存储电容的液晶显示元件		
公开(公告)号	EP1136873B1	公开(公告)日	2006-06-14
申请号	EP2001105303	申请日	2001-03-06
[标]申请(专利权)人(译)	株式会社日立制作所		
申请(专利权)人(译)	HITACHI , LTD.		
当前申请(专利权)人(译)	HITACHI , LTD.		
发明人	OOTSU, RYOUICHI, HITACHI LTD., INTELL.PROP.GROUP OHGIICHI, KIMITOSHI, HITACHI LTD.INTELL.PROP.GROUP		
IPC分类号	G02F1/1362 G02F1/1343		
CPC分类号	G02F1/136213 G02F1/134336 G02F2201/123		
优先权	2000061059 2000-03-06 JP		
其他公开文献	EP1136873A3 EP1136873A2		
外部链接	Espacenet		

摘要(译)

液晶显示元件包括一对基板 (SUB1 , SUB2) , 夹在其间的液晶层 (CL) , 设置为与设置在其中一个基板上的栅极线交叉的栅极线 (GL) 和漏极线 (DL) , 薄膜晶体管 (TFT) 设置在栅极和漏极线的交叉处 , 像素电极 (ITO1) 设置在由两个相邻栅极线和两个相邻漏极线围绕的区域中 , 公共电极 (ITO2) 设置在另一个基板上。液晶显示元件还设置有设置在像素电极下方的存储线 (STL) , 其间插入有绝缘层以在它们之间形成电容。每个像素电极在其面对存储线的部分中形成有开口 (ALC) 。

